

24 W BTL OR 2 X 12 WATT STEREO CAR RADIO POWER AMPLIFIER

GENERAL DESCRIPTION

The TDA1518BQ is an integrated class-B output amplifier in a 13-lead single-in-line (SIL) plastic power package. The device is primarily developed for car radio applications.

FEATURES

- Requires very few external components
- Flexibility in use — stereo as well as mono BTL
- High output power (without bootstrap)
- Low offset voltage at output (important for BTL)
- Fixed gain
- Good ripple rejection
- Mute/stand-by switch
- Load dump protection
- A.C. and d.c. short-circuit-safe to ground and V_P
- Thermally protected
- Reverse polarity safe
- Capability to handle high energy on outputs ($V_P = 0$ V)
- No switch-on/switch-off plop
- Flexible leads
- Low thermal resistance
- Identical inputs (inverting and non-inverting)
- Compatible with TDA1516BQ (except gain)

QUICK REFERENCE DATA

parameter	conditions	symbol	min.	typ.	max.	unit
Supply voltage range						
operating		V_P	6,0	14,4	18,0	V
non-operating		V_P	—	—	30,0	V
load dump		V_P	—	—	45,0	V
Repetitive peak output current		I_{ORM}	—	—	4	A
Total quiescent current		I_{tot}	—	30	—	mA
Stand-by current		I_{sb}	—	0,1	100	μ A
Switch-on current		I_{sw}	—	—	40	μ A
Input impedance		$ Z_I $	25	—	—	$k\Omega$
BTL		$ Z_I $	50	—	—	$k\Omega$
stereo						
Stereo application						
Output power	THD = 10%; 4 Ω	P_o	—	6	—	W
	THD = 10%; 2 Ω	P_o	—	11	—	W
Channel separation		α	40	—	—	dB
Noise output voltage		$V_{no(rms)}$	—	150	—	μ V
BTL application						
Output power	THD = 10%; 4 Ω	P_o	—	22	—	W
Supply voltage	$R_S = 0 \Omega$;	RR	—	—	—	
ripple rejection	$f = 100$ Hz to 10 kHz	$ \Delta V_{O1} $	48	—	—	dB
D.C. output offset voltage			—	—	250	mV

PACKAGE OUTLINE

13-lead SIL-bent-to-DIL; plastic power (SOT141C).

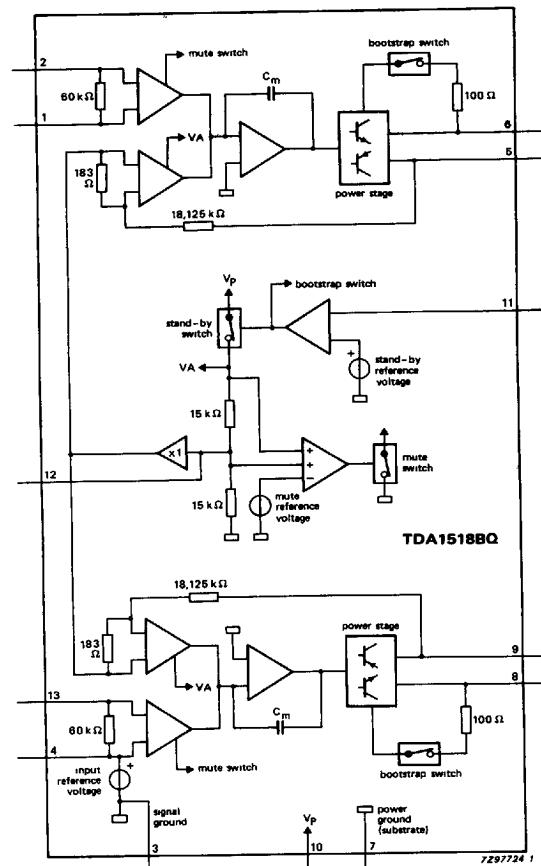


Fig. 1 Block diagram.

PINNING

1	-INV1	non-inverting input 1	8	BS2	bootstrap 2
2	INV	inverting input	9	OUT2	output 2
3	GND1	ground (signal)	10	Vp	supply voltage
4	V _{ref}	reference voltage	11	M/SS	mute/stand-by switch
5	OUT1	output 1	12	RR	supply voltage ripple rejection
6	BS1	bootstrap 1	13	-INV2	non-inverting input 2
7	GND2	ground (substrate)			

FUNCTIONAL DESCRIPTION

The TDA1518BQ contains two identical amplifiers with differential input stages. This device can be used for stereo or bridge applications. The gain of each amplifier is fixed at 40 dB. A special feature of this device is the mute/stand-by switch which has the following features:

- low stand-by current (< 100 μ A)
- low mute/stand-by switching current (low cost supply switch)
- mute condition

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

parameter	conditions	symbol	min.	max.	unit
Supply voltage operating		V_P	—	18	V
non-operating		V_P	—	30	V
load dump	during 50 ms; $t_r \geq 2.5$ ms	V_P	—	45	V
A.C. and d.c. short-circuit-safe voltage		V_{PSC}	—	18	V
Reverse polarity		V_{PR}	—	6	V
Energy handling capability at outputs	$V_P = 0$ V		—	200	mJ
Non-repetitive peak output current		I_{OSM}	—	6	A
Repetitive peak output current		I_{ORM}	—	4	A
Total power dissipation	see Fig. 2	P_{tot}	—	25	W
Crystal temperature		T_c	—	150	°C
Storage temperature range		T_{stg}	-55	+ 150	°C

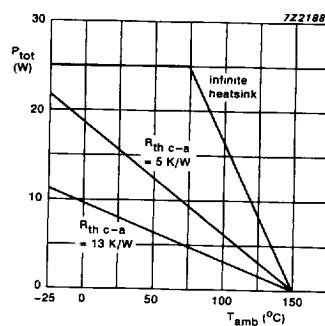


Fig. 2 Power derating curve.

D.C. CHARACTERISTICS (note 1)V_p = 14.4 V; T_{amb} = 25 °C; unless otherwise specified

parameter	conditions	symbol	min.	typ.	max.	unit
Supply						
Supply voltage range	note 2	V _p	6,0	14,4	18,0	V
Quiescent current		I _P	—	30	*	mA
D.C. output voltage at approximately V _p /2	note 3	V _O	—	6,8	—	V
D.C. output offset voltage		ΔV ₅₋₉	—	—	200	mV
Mute/stand-by switch						
Switch-on voltage level		V _{ON}	8,5	—	—	V
Mute condition		V _{mute}	3,0	—	6,4	V
Output signal in mute position	V _I = 1 V (max.); f = 20 Hz to 15 kHz	V _O	—	*	20	mV
D.C. output offset voltage		ΔV ₅₋₉	—	—	250	mV
Stand-by condition		V _{sb}	0	—	2	V
D.C. current in stand-by condition		I _{sb}	—	—	100	μA
Switch-on current		I _{sw}	—	12	40	μA

* Value to be fixed.

A.C. CHARACTERISTICS

$V_p = 14.4 \text{ V}$; $R_L = 4 \Omega$; $f = 1 \text{ kHz}$; $T_{\text{amb}} = 25^\circ\text{C}$; unless otherwise specified

parameter	conditions	symbol	min.	typ.	max.	unit
Stereo application	note 1					
Output power	note 4; THD = 0,5% THD = 10%	P_o	4 5,5	5 6,0	—	W
	notes 4 and 5; THD = 10%	P_o	6	7	—	W
Output power at $R_L = 2 \Omega$	note 4; THD = 0,5% THD = 10%	P_o	7,75 10	8,5 11	—	W
	notes 4 and 5; THD = 10%	P_o	10,5	12,0	—	W
Low frequency roll-off	note 6; -3 dB	f_L	—	45	—	Hz
High frequency roll-off	-1 dB	f_H	20	—	—	kHz
Closed loop voltage gain		G_v	39	40	41	dB
Supply voltage ripple rejection: ON mute stand-by	note 7	RR	48	—	—	dB
		RR	48	—	—	dB
		RR	80	—	—	dB
Input impedance		$ Z_i $	50	60	75	k Ω
Noise output voltage: ON ON mute	note 8; $R_S = 0 \Omega$ $R_S = 10 \text{ k}\Omega$	$V_{no(\text{rms})}$	—	150 250	— 500	μV
	note 9	$V_{no(\text{rms})}$	—	120	—	μV
Channel separation	$R_S = 10 \text{ k}\Omega$	α	40	—	—	dB
Channel balance		G_v	—	0.1	1	dB

A.C. CHARACTERISTICS (continued)

parameter	conditions	symbol	min.	typ.	max.	unit
BTL application	note 10					
Output power	THD = 0,5%	P _O	15,5	17,0	—	W
	THD = 10%	P _O	20	22	—	W
	note 5; THD = 10%	P _O	21	24	—	W
Output power at V _p = 13,2 V	THD = 0,5%	P _O	—	13,5	—	W
	THD = 10%	P _O	—	17	—	W
	note 5; THD = 10%	P _O	—	19	—	W
Power bandwidth	THD = 0,5% P _O = 15 W	B _W	—	20 to 15 000	—	Hz
Low frequency roll-off	note 6; —3 dB	f _L	—	45	—	Hz
High frequency roll-off	—1 dB	f _H	20	—	—	kHz
Closed loop voltage gain		G _V	45	46	47	dB
Supply voltage ripple rejection:	note 7	RR	48	—	—	dB
ON		RR	48	—	—	dB
mute		RR	80	—	—	dB
stand-by		Z	25	30	38	kΩ
Input impedance						
Noise output voltage:	note 8;	V _{no(rms)}	—	200	—	μV
ON	R _S = 0 Ω	V _{no(rms)}	—	350	700	μV
ON	R _S = 10 kΩ	V _{no(rms)}	—	120	—	μV
mute	note 9	dV/dt	—	—	*	V/ms
Switch-on/switch-off behaviour						

Notes to the characteristics

1. All characteristics, for stereo application are measured using the circuit shown in Fig. 3.
2. The circuit is d.c. adjusted at V_p = 6 V to 18 V and a.c. operating at V_p = 8,1 V to 18 V.
3. At 18 V < V_p < 30 V the d.c. output voltage $\leq V_p/2$.
4. Output power is measured directly at the output pins of the IC.
5. With bootstrap and a 100 kΩ resistor from pin 12 to the positive supply voltage (V_p), value of bootstrap capacitor is 47 μF.
6. Frequency response externally fixed.
7. Ripple rejection measured at the output with a source impedance of 0 Ω (maximum ripple amplitude of 2 V) and a frequency between 1 kHz and 10 kHz.
8. Noise voltage measured in a bandwidth of 20 Hz to 20 kHz.
9. Noise output voltage independent of R_S (V_I = 0 V).
10. All characteristics, for BTL application are measured using the circuit shown in Fig. 4.

* Value to be fixed.

APPLICATION INFORMATION

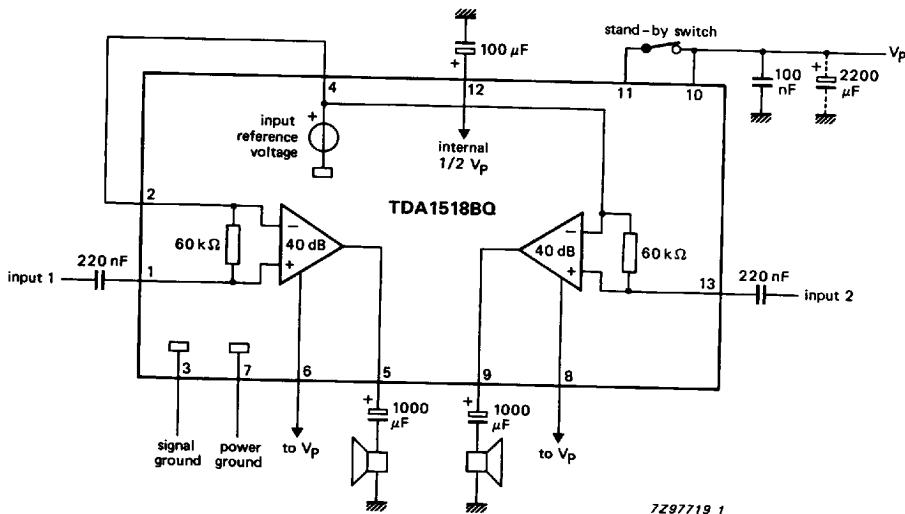


Fig. 3 Stereo application circuit diagram.

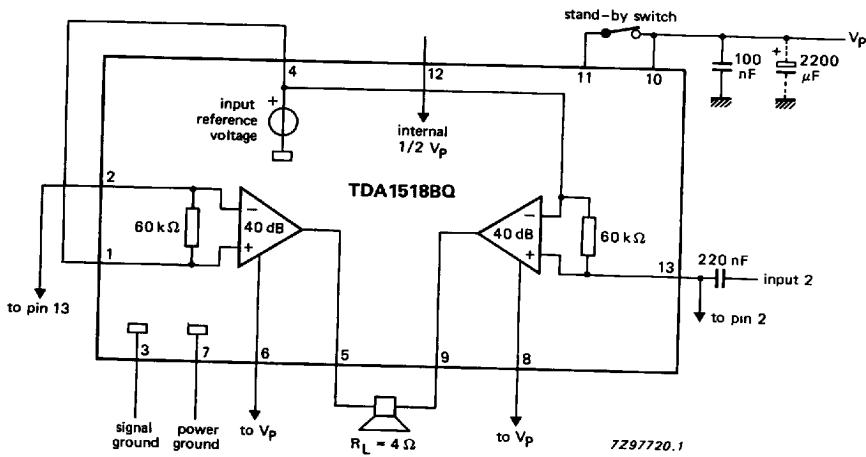


Fig. 4 BTL application circuit diagram (without bootstrapping).